Axel Persson

List of Publications by Year in descending order

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Version: 2024-02-01

687363 713466 26 478 13 21 h-index citations g-index papers 26 26 26 641 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	Individual Defects in InAs/InGaAsSb/GaSb Nanowire Tunnel Field-Effect Transistors Operating below 60 mV/decade. Nano Letters, 2017, 17, 4373-4380.	9.1	85
2	In situ analysis of catalyst composition during gold catalyzed GaAs nanowire growth. Nature Communications, 2019, 10, 4577.	12.8	49
3	Vertical InAs/InGaAs Heterostructure Metal–Oxide–Semiconductor Field-Effect Transistors on Si. Nano Letters, 2017, 17, 6006-6010.	9.1	37
4	GaAsP Nanowires Grown by Aerotaxy. Nano Letters, 2016, 16, 5701-5707.	9.1	36
5	Independent Control of Nucleation and Layer Growth in Nanowires. ACS Nano, 2020, 14, 3868-3875.	14.6	31
6	Polymerâ€6upported Palladium(II) Carbene Complexes: Catalytic Activity, Recyclability, and Selectivity in Câ^'H Acetoxylation of Arenes. Chemistry - A European Journal, 2017, 23, 8457-8465.	3.3	25
7	High-Performance Vertical III-V Nanowire MOSFETs on Si With g _m > 3 mS/νm. IEEE Electron Device Letters, 2020, 41, 1161-1164.	3.9	22
8	In situ XAS study of the local structure and oxidation state evolution of palladium in a reduced graphene oxide supported Pd(ii) carbene complex during an undirected C–H acetoxylation reaction. Catalysis Science and Technology, 2019, 9, 2025-2031.	4.1	20
9	Kinetics of Au–Ga Droplet Mediated Decomposition of GaAs Nanowires. Nano Letters, 2019, 19, 3498-3504.	9.1	18
10	A Pd ^{II} Carbene Complex with Anthracene Sideâ€Arms for Ï€â€Stacking on Reduced Graphene Oxide (rGO): Activity towards Undirected C–H Oxygenation of Arenes. European Journal of Inorganic Chemistry, 2018, 2018, 4742-4746.	2.0	17
11	Epitaxial growth of $\langle i \rangle \hat{l}^2 \langle i \rangle$ -Ga2O3 by hot-wall MOCVD. AIP Advances, 2022, 12, .	1.3	17
12	<i>n</i> -type doping and morphology of GaAs nanowires in Aerotaxy. Nanotechnology, 2018, 29, 285601.	2.6	15
13	Directed Câ^'H Halogenation Reactions Catalysed by Pd ^{II} Supported on Polymers under Batch and Continuous Flow Conditions. Chemistry - A European Journal, 2019, 25, 13591-13597.	3.3	14
14	Mg-doping and free-hole properties of hot-wall MOCVD GaN. Journal of Applied Physics, 2022, 131, .	2.5	14
15	Compressively-strained GaSb nanowires with core-shell heterostructures. Nano Research, 2020, 13, 2517-2524.	10.4	13
16	Tuning of Source Material for InAs/InGaAsSb/GaSb Application-Specific Vertical Nanowire Tunnel FETs. ACS Applied Electronic Materials, 2020, 2, 2882-2887.	4.3	11
17	Aerotaxy: gas-phase epitaxy of quasi 1D nanostructures. Nanotechnology, 2021, 32, 025605.	2.6	11
18	Observing growth under confinement: Sn nanopillars in porous alumina templates. Nanoscale Advances, 2019, 1, 4764-4771.	4.6	8

#	Article	IF	CITATION
19	Impact of in situ NH3 pre-treatment of LPCVD SiN passivation on GaN HEMT performance. Semiconductor Science and Technology, 2022, 37, 035011.	2.0	8
20	Template-assisted vapour–liquid–solid growth of InP nanowires on (001) InP and Si substrates. Nanoscale, 2020, 12, 888-894.	5.6	7
21	Kinetic Engineering of Wurtzite and Zinc-Blende AlSb Shells on InAs Nanowires. Nano Letters, 2018, 18, 5775-5781.	9.1	6
22	Electron Tomography Reveals the Droplet Covered Surface Structure of Nanowires Grown by Aerotaxy. Small, 2018, 14, e1801285.	10.0	5
23	Time-resolved compositional mapping during in situ TEM studies. Ultramicroscopy, 2021, 222, 113193.	1.9	4
24	Calculation of Hole Concentrations in Zn Doped GaAs Nanowires. Nanomaterials, 2020, 10, 2524.	4.1	2
25	Coherently strained and dislocationâ€free architectured AlGaN/GaN submicronâ€sized structures. Nano Select, 0, , .	3.7	2
26	Real-time in-situ Investigation of III-V Nanowire Growth using Custom-designed Hybrid Chemical Vapor Deposition-TEM. Microscopy and Microanalysis, 2017, 23, 1716-1717.	0.4	1